

**DYNAMIC CHARACTERISTICS**

**APT10078BFL S\_FLL**

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$ $V_{DS} = 25V$ $f = 1\text{ MHz}$		2525		pF
$C_{oss}$	Output Capacitance			430		
$C_{rss}$	Reverse Transfer Capacitance			75		
$Q_g$	Total Gate Charge ③	$V_{GS} = 10V$ $V_{DD} = 500V$ $I_D = 14A @ 25^\circ C$		95		nC
$Q_{gs}$	Gate-Source Charge			12		
$Q_{gd}$	Gate-Drain ("Miller") Charge			60		
$t_{d(on)}$	Turn-on Delay Time	<b>RESISTIVE SWITCHING</b> $V_{GS} = 15V$ $V_{DD} = 500V$ $I_D = 14A @ 25^\circ C$ $R_G = 1.6\Omega$		9		ns
$t_r$	Rise Time			8		
$t_{d(off)}$	Turn-off Delay Time			30		
$t_f$	Fall Time			9		
$E_{on}$	Turn-on Switching Energy ⑥	<b>INDUCTIVE SWITCHING @ 25°C</b> $V_{DD} = 667V$ $V_{GS} = 15V$ $I_D = 14A$ , $R_G = 3\Omega$		355		$\mu J$
$E_{off}$	Turn-off Switching Energy			75		
$E_{on}$	Turn-on Switching Energy ⑥	<b>INDUCTIVE SWITCHING @ 125°C</b> $V_{DD} = 667V$ $V_{GS} = 15V$ $I_D = 14A$ , $R_G = 3\Omega$		740		
$E_{off}$	Turn-off Switching Energy			95		

**SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS**

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
$I_S$	Continuous Source Current (Body Diode)			14	Amps
$I_{SM}$	Pulsed Source Current ① (Body Diode)			56	Amps
$V_{SD}$	Diode Forward Voltage ② ( $V_{GS} = 0V$ , $I_S = I_D - 14A$ )			1.3	Volts
$dv/dt$	Peak Diode Recovery $dv/dt$ ⑤			18	V/ns
$t_{rr}$	Reverse Recovery Time ( $I_S = I_D - 14A$ , $di/dt = 100A/\mu s$ )	$T_j = 25^\circ C$		210	ns
		$T_j = 125^\circ C$		710	
$Q_{rr}$	Reverse Recovery Charge ( $I_S = I_D - 14A$ , $di/dt = 100A/\mu s$ )	$T_j = 25^\circ C$		1.0	$\mu C$
		$T_j = 125^\circ C$		3.6	
$I_{RRM}$	Peak Recovery Current ( $I_S = I_D - 14A$ , $di/dt = 100A/\mu s$ )	$T_j = 25^\circ C$		9.8	Amps
		$T_j = 125^\circ C$		14	

**THERMAL CHARACTERISTICS**

Symbol	Characteristic	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to Case			0.31	$^\circ C/W$
$R_{\theta JA}$	Junction to Ambient			40	

① Repetitive Rating: Pulse width limited by maximum junction temperature

② Pulse Test: Pulse width < 380  $\mu s$ , Duty Cycle < 2%

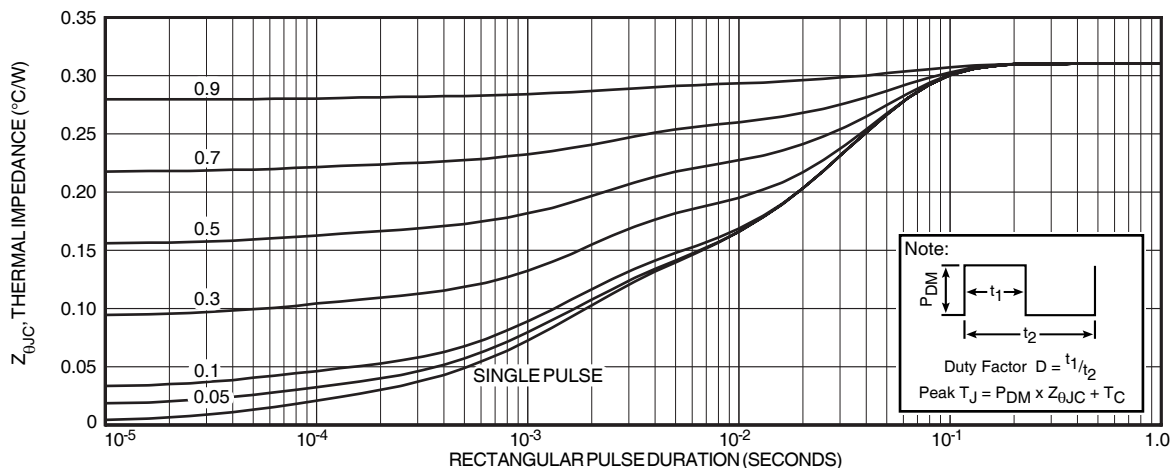
③ See MIL-STD-750 Method 3471

④ Starting  $T_j = +25^\circ C$ ,  $L = 13.27mH$ ,  $R_G = 25\Omega$ , Peak  $I_L = 14A$

⑤  $dv/dt$  numbers reflect the limitations of the test circuit rather than the device itself.  $I_S \leq I_D - 14A$   $di/dt \leq 700A/\mu s$   $V_R \leq 1000$   $T_j \leq 150^\circ C$

⑥  $E_{on}$  includes diode reverse recovery. See figures 18, 20.

**APT Reserves the right to change, without notice, the specifications and information contained herein.**



**FIGURE 1, MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs PULSE DURATION**

# Typical Performance Curves

APT10078BFL S<sub>FL</sub>L

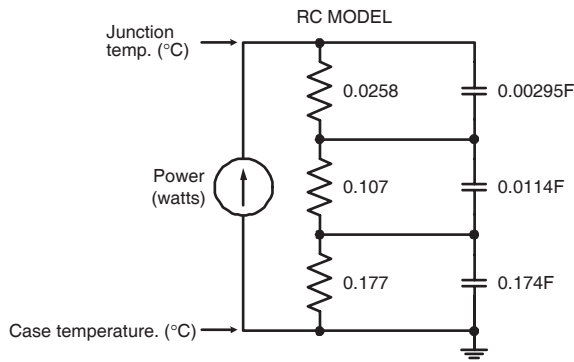


FIGURE 2, TRANSIENT THERMAL IMPEDANCE MODEL

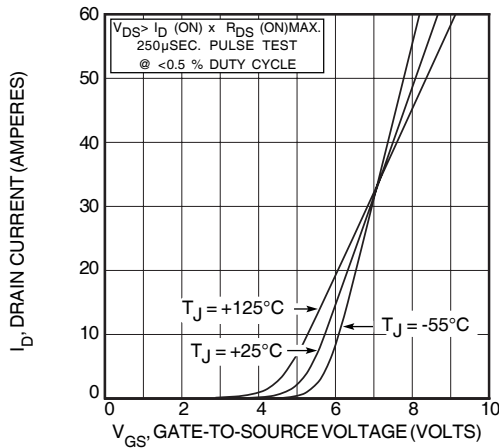


FIGURE 4, TRANSFER CHARACTERISTICS

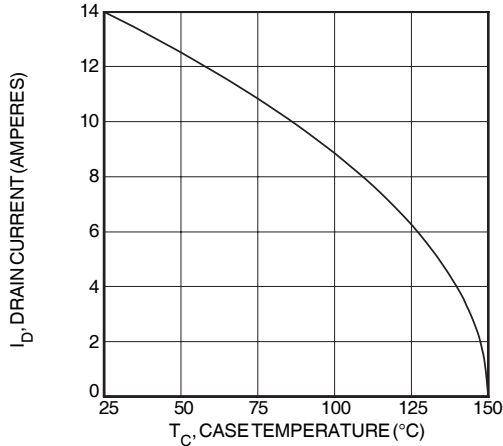


FIGURE 6, MAXIMUM DRAIN CURRENT vs CASE TEMPERATURE

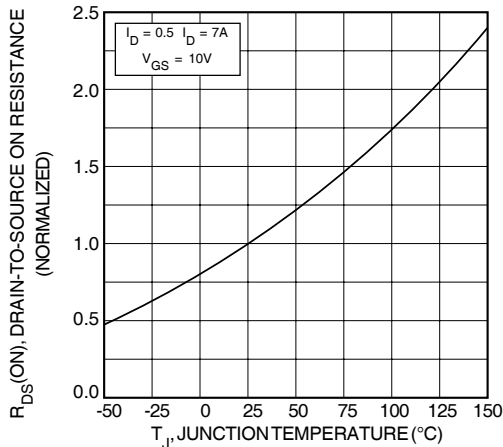


FIGURE 8, ON-RESISTANCE vs. TEMPERATURE

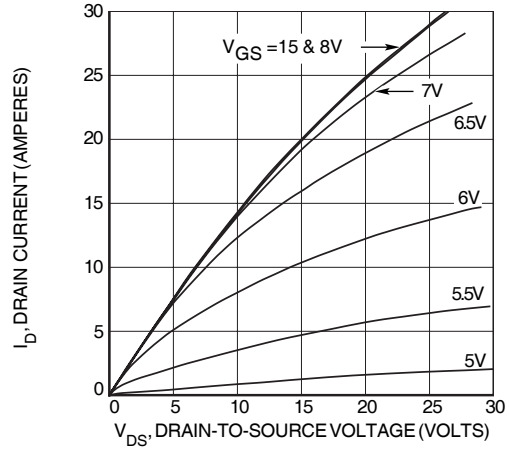


FIGURE 3, LOW VOLTAGE OUTPUT CHARACTERISTICS

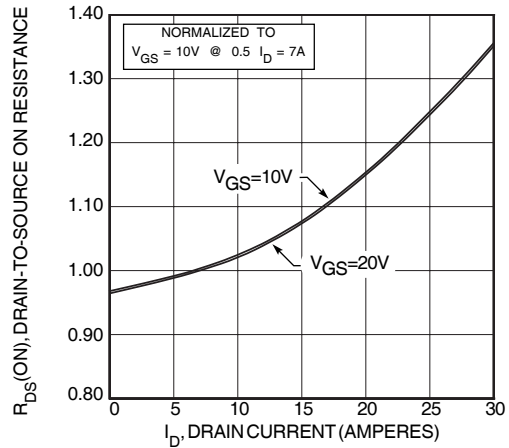


FIGURE 5,  $R_{DS(ON)}$  vs DRAIN CURRENT

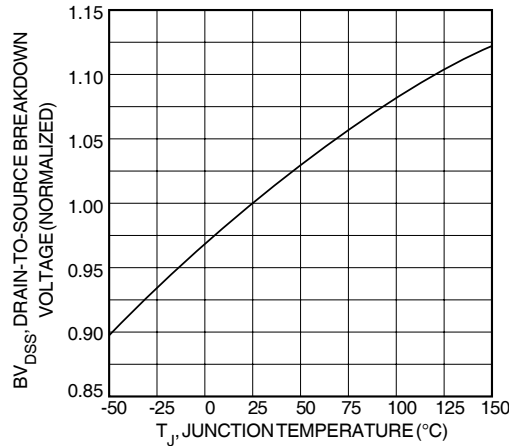


FIGURE 7, BREAKDOWN VOLTAGE vs TEMPERATURE

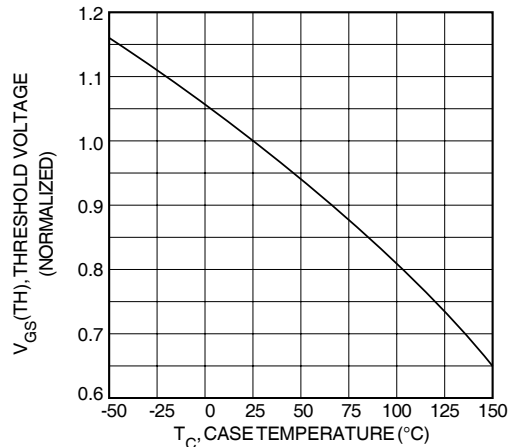


FIGURE 9, THRESHOLD VOLTAGE vs TEMPERATURE

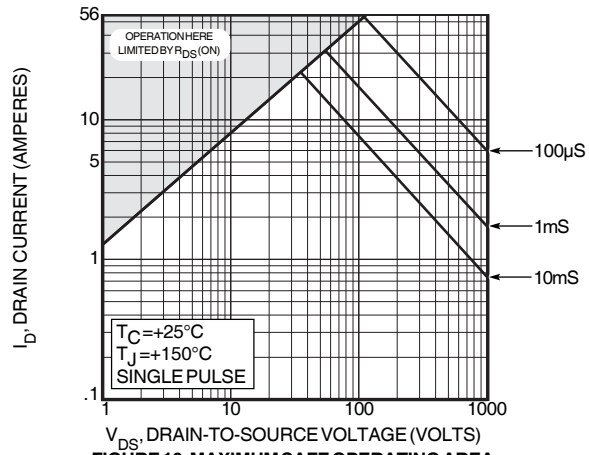


FIGURE 10, MAXIMUM SAFE OPERATING AREA

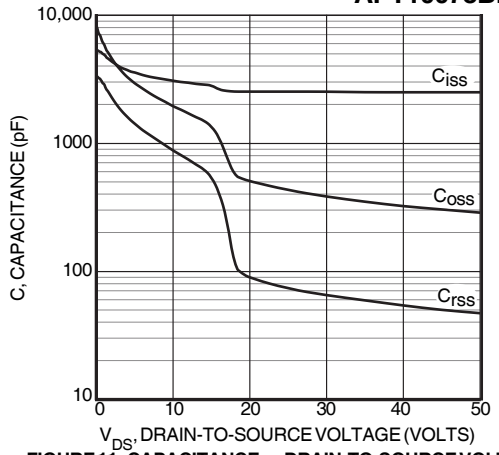


FIGURE 11, CAPACITANCE vs DRAIN-TO-SOURCE VOLTAGE

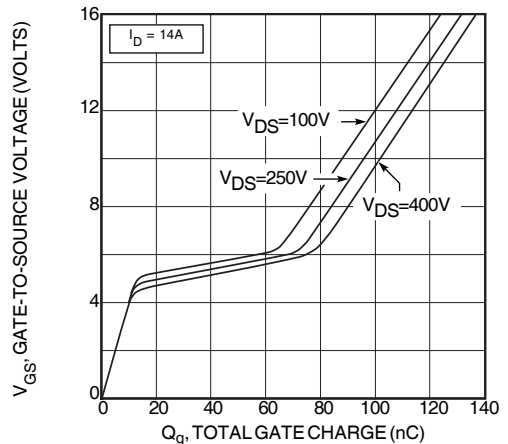


FIGURE 12, GATE CHARGES vs GATE-TO-SOURCE VOLTAGE

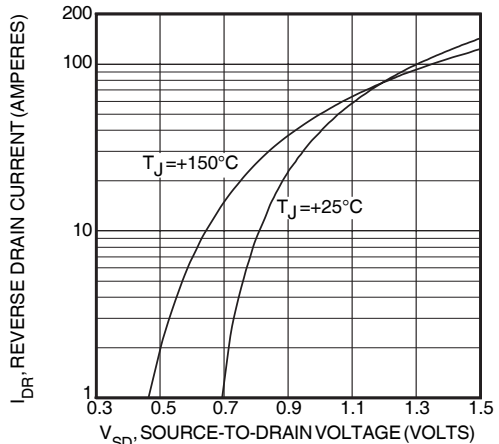


FIGURE 13, SOURCE-DRAIN DIODE FORWARD VOLTAGE

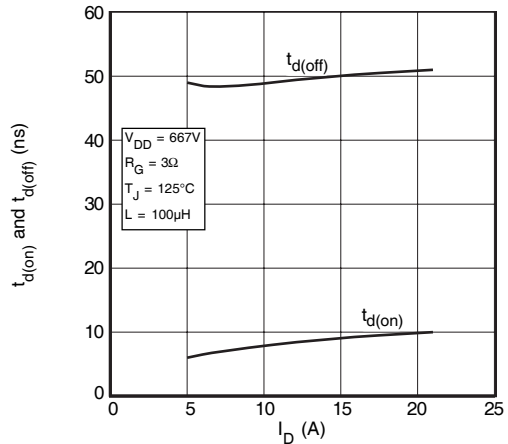


FIGURE 14, DELAY TIMES vs CURRENT

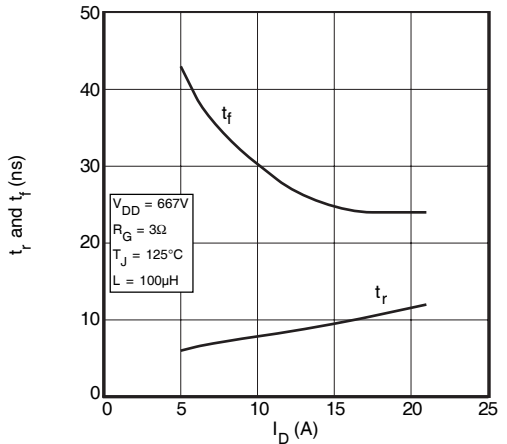


FIGURE 15, RISE AND FALL TIMES vs CURRENT

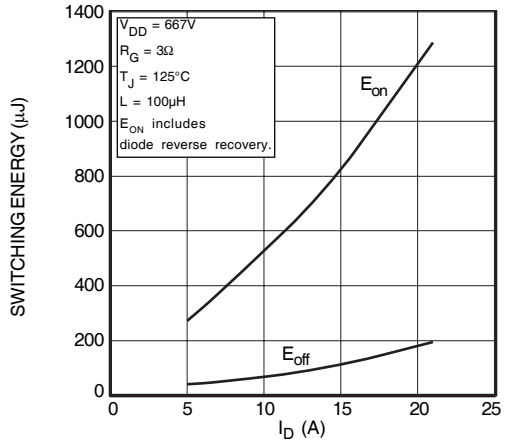


FIGURE 16, SWITCHING ENERGY vs CURRENT

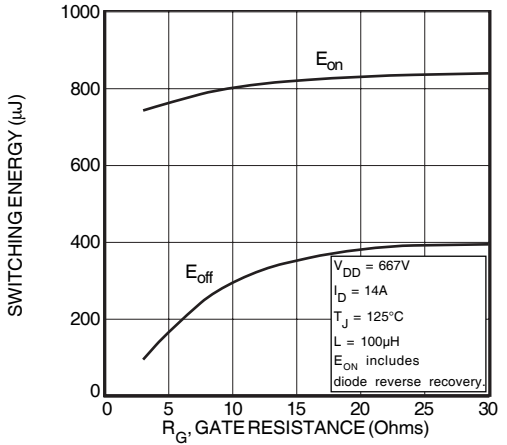


FIGURE 17, SWITCHING ENERGY vs. GATE RESISTANCE

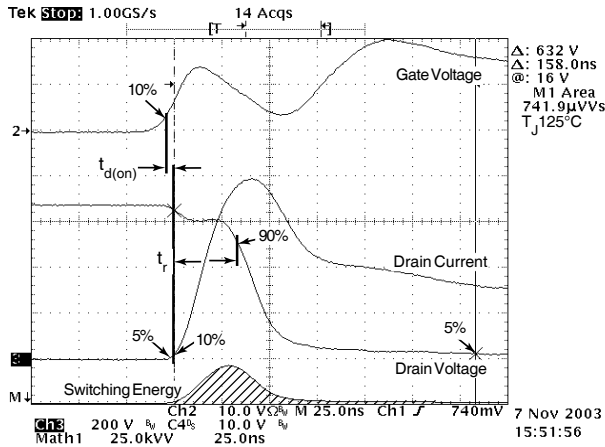


Figure 18, Turn-on Switching Waveforms and Definitions

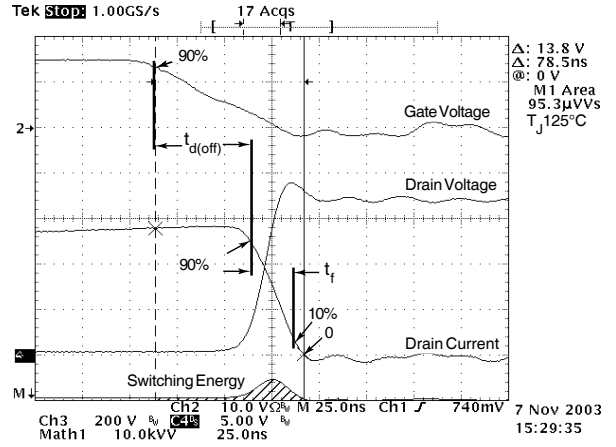


Figure 19, Turn-off Switching Waveforms and Definitions

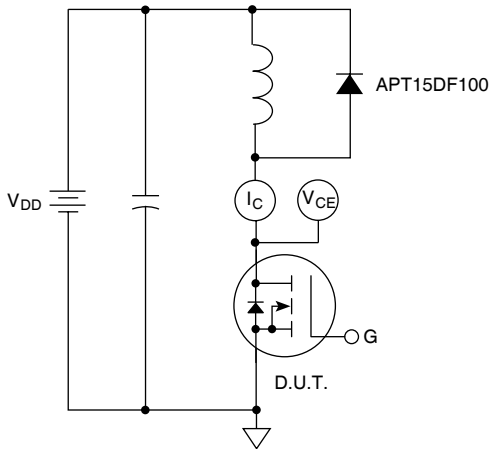
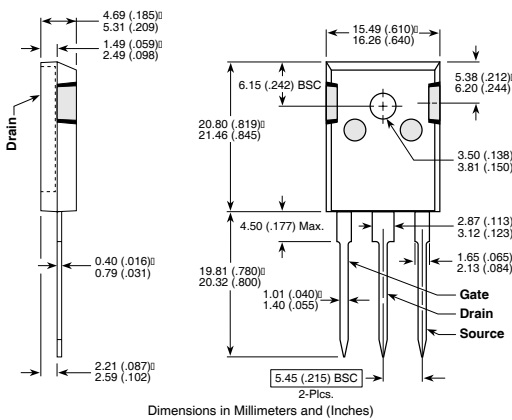
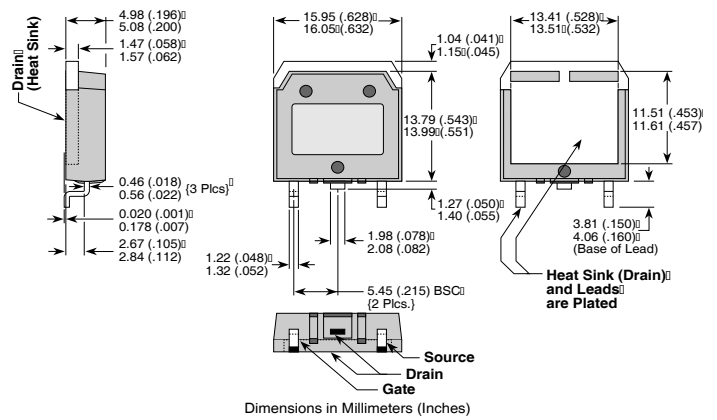


Figure 20, Inductive Switching Test Circuit

TO-247 Package Outline



D<sup>3</sup>PAK Package Outline



APT's products are covered by one or more of U.S. patents 4,895,810 5,045,903 5,089,434 5,182,234 5,019,522

5,262,336 6,503,786 5,256,583 4,748,103 5,283,202 5,231,474 5,434,095 5,528,058 and foreign patents. US and Foreign patents pending. All Rights Reserved.

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